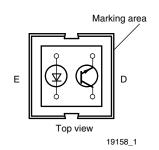


www.vishay.com

Vishay Semiconductors

Reflective Optical Sensor with Transistor Output





DESCRIPTION

The CNY70 is a reflective sensor that includes an infrared emitter and phototransistor in a leaded package which blocks visible light.

FEATURES

· Package type: leaded

• Detector type: phototransistor

• Dimensions (L x W x H in mm): 7 x 7 x 6

• Peak operating distance: < 0.5 mm

• Operating range within > 20 % relative collector current: 0 mm to 5 mm

Typical output current under test: I_C = 1 mA

• Emitter wavelength: 950 nm

· Daylight blocking filter

• Lead (Pb)-free soldering released

 Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



 Optoelectronic scanning and switching devices i.e., index sensing, coded disk scanning etc. (optoelectronic encoder assemblies).

PRODUCT SUMMARY				
PART NUMBER	DISTANCE FOR MAXIMUM CTR _{rel} (1) (mm)	DISTANCE RANGE FOR RELATIVE I _{out} > 20 % (mm)	TYPICAL OUTPUT CURRENT UNDER TEST ⁽²⁾ (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED
CNY70	0	0 to 5	1	Yes

Notes

- $^{(1)}$ CTR: current transfere ratio, I_{out}/I_{in}
- (2) Conditions like in table basic charactristics/sensors

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	VOLUME (1)	REMARKS		
CNY70	Tube	MOQ: 4000 pcs, 80 pcs/tube	-		

Note

(1) MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION SYMBOL VALUE		VALUE	UNIT	
COUPLER					
Total power dissipation	T _{amb} ≤ 25 °C	P _{tot}	200	mW	
Ambient temperature range		T _{amb}	- 40 to + 85	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	Distance to case 2 mm, t £ 5 s	T _{sd}	260	°C	
INPUT (EMITTER)					
Reverse voltage		V_{R}	5	V	
Forward current		I _F	50	mA	
Forward surge current	t _p ≤ 10 μs	I _{FSM}	3	А	
Power dissipation	T _{amb} ≤ 25 °C	P _V	100	mW	
Junction temperature		T _j	100	°C	



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
OUTPUT (DETECTOR)					
Collector emitter voltage		V _{CEO}	32	V	
Emitter collector voltage		V _{ECO}	7	V	
Collector current		I _C	50	mA	
Power dissipation	T _{amb} ≤ 25 °C	P _V	100	mW	
Junction temperature		Tj	100	°C	

ABSOLUTE MAXIMUM RATINGS

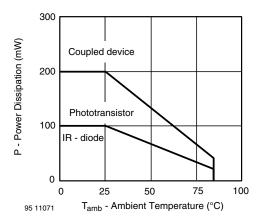


Fig. 1 - Power Dissipation vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
COUPLER	COUPLER					
Collector current	$V_{CE} = 5 \text{ V}, I_F = 20 \text{ mA}, d = 0.3 \text{ mm (figure 1)}$	I _C ⁽²⁾	0.3	1.0		mA
Cross talk current	$V_{CE} = 5 \text{ V}, I_F = 20 \text{ mA}, \text{ (figure 2)}$	I _{CX} (3)			600	nA
Collector emitter saturation voltage	$I_F = 20 \text{ mA}, I_C = 0.1 \text{ mA},$ d = 0.3 mm (figure 1)	V _{CEsat} (2)			0.3	V
INPUT (EMITTER)						
Forward voltage	I _F = 50 mA	V_{F}		1.25	1.6	V
Radiant intensity	$I_F = 50 \text{ mA}, t_p = 20 \text{ ms}$	l _e			7.5	mW/sr
Peak wavelength	I _F = 100 mA	λ_{P}	940			nm
Virtual source diameter	Method: 63 % encircled energy	d		1.2		mm
OUTPUT (DETECTOR)						
Collector emitter voltage	I _C = 1 mA	V_{CEO}	32			V
Emitter collector voltage	I _E = 100 μA	V_{ECO}	5			V
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}, E = 0 \text{ Ix}$	I _{CEO}			200	nA

Notes

 $^{^{(1)}}$ Measured with the "Kodak neutral test card", white side with 90 % diffuse reflectance

⁽²⁾ Measured without reflecting medium



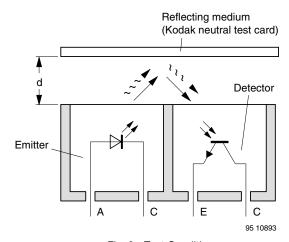


Fig. 2 - Test Condition

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

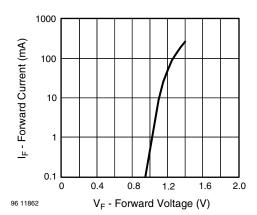


Fig. 3 - Forward Current vs. Forward Voltage

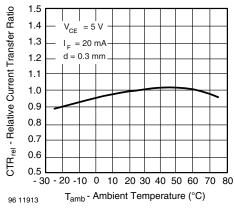


Fig. 4 - Relative Current Transfer Ratio vs. Ambient Temperature

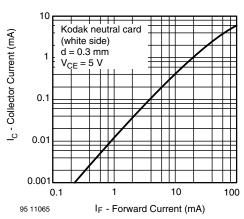


Fig. 5 - Collector Current vs. Forward Current

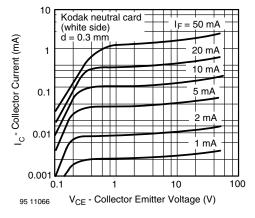


Fig. 6 - Collector Current vs. Collector Emitter Voltage



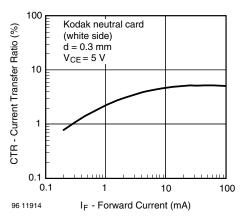


Fig. 7 - Current Transfer Ratio vs. Forward Current

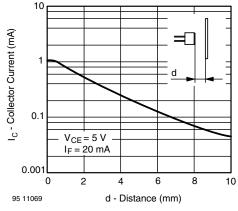


Fig. 9 - Collector Current vs. Distance

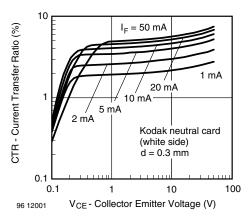


Fig. 8 - Current Transfer Ratio vs. Collector Emitter Voltage

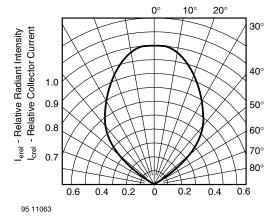


Fig. 10 - Relative Radiant Intensity/Collector Current vs.

Angular Displacement

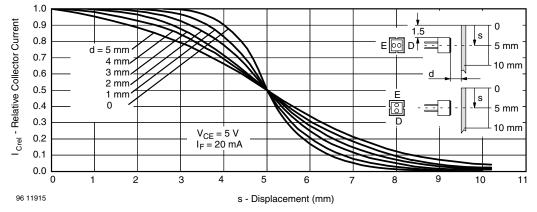
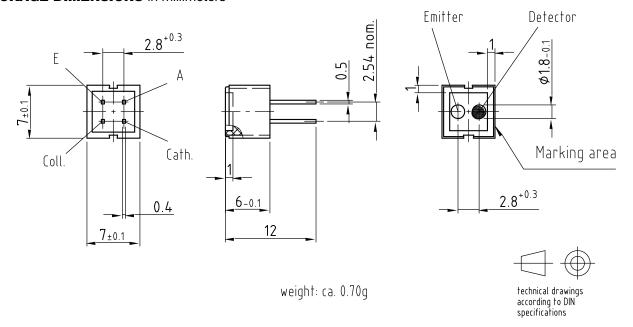


Fig. 11 - Relative Collector Current vs. Displacement

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PACKAGE DIMENSIONS in millimeters

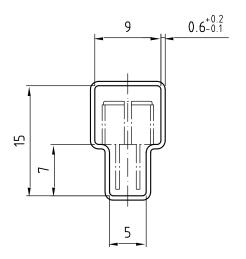


Drawing-No.: 6.544-5062.01-4

Issue: 6; 03.05.06

95 11345

TUBE DIMENSIONS in millimeters



With rubber stopper Tolerance: ±0.5mm Length: 575±1mm

Drawing-No.: 9.700-5097.01-4

Issue: 1; 25.02.00

20291



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